

Charlotte Zborowski

List of Publications by Year in descending order

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16
papers

161
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1478280

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1199470

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docs citations

16
times ranked

136
citing authors

#	ARTICLE	IF	CITATIONS
1	Improved depth information from routine analysis of the inelastic background of XPS and HAXPES spectra using optimized two- and three-parameter cross-sections. <i>Surface and Interface Analysis</i> , 2022, 54, 433-441.	0.8	2
2	Comparison and complementarity of QUASES-Tougaard and SESSA software. <i>Applied Surface Science</i> , 2022, 585, 152758.	3.1	3
3	High-energy x-ray photoelectron spectroscopy spectra of InP measured by Cr K α . <i>Surface Science Spectra</i> , 2022, 29, 014018.	0.3	1
4	High-energy x-ray photoelectron spectroscopy spectra of TiO ₂ measured by Cr K α . <i>Surface Science Spectra</i> , 2022, 29, 014017.	0.3	2
5	High-energy x-ray photoelectron spectroscopy spectra of Al ₂ O ₃ measured by Cr K α . <i>Surface Science Spectra</i> , 2022, 29, 014021.	0.3	1
6	High-energy x-ray photoelectron spectroscopy spectra of HfO ₂ measured by Cr K α . <i>Surface Science Spectra</i> , 2022, 29, 014019.	0.3	1
7	High-energy x-ray photoelectron spectroscopy spectra of TiN measured by Cr K α . <i>Surface Science Spectra</i> , 2022, 29, 014016.	0.3	1
8	Adsorptive behavior of phosphorus onto recycled waste biosolids after being acid leached from wastewater sludge. <i>Chemical Engineering Journal Advances</i> , 2022, 11, 100329.	2.4	3
9	HAXPES of GaN film on Si with Cr K α photons. <i>Surface Science Spectra</i> , 2021, 28, 014006.	0.3	1
10	Surface analysis in the semiconductor industry: Present use and future possibilities. <i>Surface and Interface Analysis</i> , 2020, 52, 786-791.	0.8	4
11	Theoretical study toward rationalizing inelastic background analysis of buried layers in XPS and HAXPES. <i>Surface and Interface Analysis</i> , 2019, 51, 857-873.	0.8	23
12	Determination of the input parameters for inelastic background analysis combined with HAXPES using a reference sample. <i>Applied Surface Science</i> , 2018, 432, 60-70.	3.1	24
13	Quantitative determination of elemental diffusion from deeply buried layers by photoelectron spectroscopy. <i>Journal of Applied Physics</i> , 2018, 124, .	1.1	22
14	Analysis of buried interfaces in multilayer device structures with hard XPS (HAXPES) using a CrK α source. <i>Surface and Interface Analysis</i> , 2018, 50, 1158-1162.	0.8	23
15	Effective inelastic scattering cross-sections for background analysis in HAXPES of deeply buried layers. <i>Applied Surface Science</i> , 2017, 402, 78-85.	3.1	33
16	Quantitative spectromicroscopy from inelastically scattered photoelectrons in the hard X-ray range. <i>Applied Physics Letters</i> , 2016, 109, .	1.5	17